

IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently amended) A light emitting device comprising:

a plurality of pixels provided with light emitting elements; and

a thin film transistor and a pixel electrode electrically connected to the thin film transistor provided at each of the plurality of pixels,

wherein an insulating film is provided over the thin film transistor and the pixel electrode is provided over the insulating film, [[and]]

wherein the insulating film includes an opening portion, a side surface of which is curved at a light emitting region, and

wherein each of the light emitting elements comprises the pixel electrode, a light emitting layer, and an opposed electrode.

2. (Original) The light emitting device according to claim 1, wherein the pixel electrode comprises an oxide conductive film.

3. (Original) The light emitting device according to claim 1, wherein the insulating film is a photosensitive resin film.

4. (Original) The light emitting device according to claim 1, wherein the opening portion has a shape of a groove.

5. (Original) The light emitting device according to claim 1, wherein the opening portion has a circular shape.

6. (Original) The light emitting device according to claim 1, wherein the opening portion has a shape of a lattice.

7. (Currently amended) A light emitting device comprising:
a plurality of pixels provided with light emitting elements; and
a thin film transistor and a pixel electrode electrically connected to the thin film transistor provided at each of the plurality of pixels,

wherein an insulating film is provided over the thin film transistor and the pixel electrode is provided over the insulating film, [[and]]

wherein the insulating film includes an opening portion a side surface of which is curved at a light emitting region and the pixel electrode covers, a side surface of the opening portion, and
wherein each of the light emitting elements comprises the pixel electrode, a light emitting
layer, and an opposed electrode.

8. (Original) The light emitting device according to claim 7, wherein the pixel electrode comprises an oxide conductive film.

9. (Original) The light emitting device according to claim 7, wherein the insulating film is a photosensitive resin film.

10. (Original) The light emitting device according to claim 7, wherein the opening portion has a shape of a groove.

11. (Original) The light emitting device according to claim 7, wherein the opening portion has a circular shape.

12. (Original) The light emitting device according to claim 7, wherein the opening portion has a shape of a lattice.

13. (Currently amended) A light emitting device comprising:
a plurality of pixels provided with light emitting elements; and
a thin film transistor and a pixel electrode electrically connected to the thin film transistor provided at each of the plurality of pixels;

wherein an insulating film is provided over the thin film transistor and the pixel electrode is provided over the insulating film, [[and]]

wherein the insulating film includes an opening portion, a side surface of which is curved at a light emitting region and a surface of the pixel electrode includes a curved face along a shape of the opening portion, and

wherein each of the light emitting elements comprises the pixel electrode, a light emitting layer, and an opposed electrode.

14. (Original) The light emitting device according to claim 13, wherein the pixel electrode comprises an oxide conductive film.

15. (Original) The light emitting device according to claim 13, wherein the insulating film is a photosensitive resin film.

16. (Original) The light emitting device according to claim 13, wherein the opening portion has a shape of a groove.

17. (Original) The light emitting device according to claim 13, wherein the opening portion has a circular shape.

18. (Original) The light emitting device according to claim 13, wherein the opening portion has a shape of a lattice.

19-28. (Canceled)

29. (Currently amended) A light emitting device comprising:

a plurality of pixels comprising a plurality of thin film transistors, a plurality of pixel electrodes, and a plurality of light emitting elements; and

a insulating film formed over the plurality of thin film transistors, wherein the plurality of pixel electrodes are formed over the insulating film,

wherein the insulating film has at least one opening portion in each of the plurality of the pixels,

wherein the opening portion has a curved side surface at a light emitting region, and

wherein each of the light emitting elements comprises the pixel electrode, a light emitting layer, and an opposed electrode.

30. (Original) A light emitting device according to claim 29, wherein the pixel electrode covers a surface of the opening portion and the insulating film.

31. (Currently amended) A light emitting device comprising:
a plurality of pixels, each of which comprises a thin film transistor, a pixel electrode electrically connected to the thin film transistor, and a light emitting element ~~over the pixel electrode; and having the pixel electrode, a light emitting layer, and an opposed electrode over the thin film transistor,~~
over the pixel electrode, a light emitting layer, and an opposed electrode over the thin film transistor,

wherein at least ~~lest~~ one island shaped insulating layer is formed in each of the plurality of pixels,

wherein the pixel electrode is formed over the island shaped insulating layer,
wherein the island shaped insulating layer has at least one opening portion and the opening portion has a curved side surface.

32. (Original) A light emitting device according to claim 31, wherein the device further comprises a data wiring, and the opening portion is formed along with the data wiring.

33. (Original) A light emitting device according to claim 31, wherein the pixel electrode covers a surface of the island shaped insulating layer and the opening portion.

34. (New) A light emitting device according to claim 1, wherein the light emitting layer comprises an organic compound.

35. (New) A light emitting device according to claim 7, wherein the light emitting layer comprises an organic compound.

36. (New) A light emitting device according to claim 13, wherein the light emitting layer comprises an organic compound.

37. (New) A light emitting device according to claim 29, wherein the light emitting layer comprises an organic compound.

38. (New) A light emitting device according to claim 31, wherein the light emitting layer comprises an organic compound.